

Phase relations in boron at pressures up to 18 GPa and temperatures up to 2200 °C

Jiaqian Qin,^{1,*} Tetsuo Irifune,¹ Haruhiko Dekura,² Hiroaki Ohfuji,¹ Norimasa Nishiyama,¹ Li Lei,¹ and Toru Shinmei¹

¹*Geodynamics Research Center, Ehime University, 2-5 Bunkyo-cho, Matsuyama, 790-8577, Japan*

²*Senior Research Fellow Center, Ehime University, 2-5 Bunkyo-cho, Matsuyama, 790-8577, Japan*

(Received 18 September 2011; revised manuscript received 28 December 2011; published 17 January 2012)

The phase relations in boron have been investigated at high pressure and high temperature using a multianvil apparatus, and the quenched sample has been analyzed by x-ray diffraction, Raman spectra, and transmission electron microscopy. We demonstrate that γ -B₂₈ can be synthesized over a wide pressure and temperature range, and α -tetragonal B₅₀ (T-B₅₀) is obtained at higher temperatures and similar pressures. The phase boundary of the β -B₁₀₆, γ -B₂₈, and T-B₅₀ is determined at pressures between 7.0 and 18 GPa and the temperatures of 500–2200 °C. The results suggest that T-B₅₀ might be an intermediate phase formed for kinetic reasons (Ostwald rule) on the way from β -B₁₀₆ to β -tetragonal B₁₉₂ (T-192) and γ -B₂₈ to T-192.

DOI: [10.1103/PhysRevB.85.014107](https://doi.org/10.1103/PhysRevB.85.014107)

PACS number(s): 64.60.–i

I. INTRODUCTION

Boron has been widely studied because of its complex polymorphism and fascinating chemical and physical properties.^{1–13} All known structures of boron and some boron-rich compounds contain B₁₂ icosahedron, which can be flexibly linked into rigid framework structures. Many previous studies of boron concentrated on the synthesis and structural characterization of pure forms. Now, probably four of the reported boron phases correspond to the pure element^{1,2,5,14–17}: α -rhombohedral B₁₂ (α -B₁₂), β -rhombohedral B₁₀₆ (β -B₁₀₆), β -tetragonal B₁₉₂ (T-192), and γ -B₂₈, but α -tetragonal B₅₀ (T-B₅₀ or T-B₅₂) are also believed to exist,¹⁸ and the single-crystal T-B₅₀ crystal was obtained by Laubengayer *et al.*¹⁹ (The crystal structure of T-B₅₀ was proposed by Hoard *et al.*^{20,21} [P42/nmm (134), $a = 8.75$ Å and $c = 5.06$ Å]). Recently, Ekimov and Zibrov²² and Kurakevych *et al.*²³ also reported that T-B₅₀ was synthesized at high pressure and high temperature (HPHT). In previous studies, Oganov *et al.*¹ gave a phase diagram of boron based on their work and previous experiments^{5,8,24} and theoretical studies.²⁵ Shirai *et al.*^{7,26,27} studied the properties of β -B₁₀₆ and the phase diagram of β -B₁₀₆ and α -B₁₂. By *ab initio* calculations, they found that at zero temperature α -B₁₂ is more stable than β -B₁₀₆. However, scientists still do not definitively know which of these two forms is the stable form. In the experiments, Zarechnaya *et al.*² reported a tentative phase boundary between β -B₁₀₆ and γ -B₂₈ based on the results of two multianvil quenched experiments and some diamond anvil cell (DAC) experiments. Parakhonskiy *et al.*³ also reported the phase relations of α -B₁₂, β -B₁₀₆, and γ -B₂₈. However, they did not see the stability of the T-192 and/or T-B₅₀ phase, and they synthesized α -B₁₂ and γ -B₂₈ in liquid metal (Pt and Au capsule might melt at their HPHT conditions). Liquid metal might act as the solvent and make the phase transition easier. Thus, the relative stability of boron phases is still experimentally unresolved at HPHT. The main reason might mainly be ascribed to the complexity of the boron crystal structures themselves.

II. EXPERIMENTAL DETAILS

In this paper, we conducted a series of experiments on the HPHT synthesis of γ -B₂₈ and T-B₅₀ from β -B₁₀₆ (claimed

purity 99.6%, Goodfellow) and examined β -B₁₀₆ at HPHT using a multianvil press (see supplementary material²⁸), and quenched the sample to ambient conditions for x-ray diffraction (XRD) and Raman spectra to investigate the phase relations of β -B₁₀₆, γ -B₂₈, and T-B₅₀. Table I shows the HPHT experiments on boron. The T-B₅₀ samples were also loaded into a focused ion beam (FIB) system (JOEL JEM-9310FIB) to prepare transmission electron microscopy (TEM) foils. The detailed procedure of FIB milling for TEM foil preparation is described elsewhere.²⁹ TEM observations were carried out using a JEOL JEM-2010, operated at 200 kV. Selected area electron diffraction (SAED) was employed to characterize T-B₅₀.

III. RESULTS AND DISCUSSION

Figure 1 shows XRD patterns and Raman spectra of the recovered products that were heated at 1600 °C for 2 h at 15 GPa and the starting materials. From the XRD patterns [Fig. 1(a)], we find that γ -B₂₈ is synthesized under this HPHT condition. Besides the γ -B₂₈, further phase identification shows that the HPHT quenched sample also contain small amounts of MgO (MgO capsule). Additionally, the XRD data of γ -boron from Oganov *et al.*¹ are also shown in Fig. 1(a), and we can find that our XRD patterns are in good agreement with the reported results. The recovered samples were also investigated using Raman spectra. The Raman spectra of the recovered sample are also different from β -B₁₀₆ [Fig. 1(b)], but are similar to that of γ -B₂₈ reported.^{2,30} Therefore, we confirm that γ -B₂₈ is successfully synthesized under this HPHT condition. In addition, we also tried to synthesize γ -B₂₈ under different HPHT conditions (Table I). XRD and Raman spectra results indicate that γ -B₂₈ can also be synthesized at 13 GPa and high temperatures of 1300 °C and 1600 °C for 2 h, 10 min, and even for just 1 min; 15 GPa and 1800 °C for 10 min; and 18 GPa and 2000 °C for 10 min. The results demonstrate that the γ -B₂₈ can be synthesized over a wide pressure and temperature (P-T) range. By indexing the powder XRD data using Powder X,³¹ the structure of quenched samples was solved to be an orthorhombic unit cell ($a = 5.0570(6)$ Å, $b = 5.6165(7)$ Å, $c = 6.9815(9)$ Å, $V = 198.29(6)$ Å³). Our results are comparable to previous experimental ($a = 5.0544$ Å, $b = 5.6199$ Å, $c = 6.9873$ Å and $a = 5.0576$ Å, $b = 5.6245$ Å, $c = 6.9884$ Å) and theoretical results.^{1,4,32,33}

TABLE I. Summary of experimental conditions and results.

Experiment no.	Conditions				Phase identified
	T ($^{\circ}\text{C}$)	P (GPa)	Capsule	Heating time	
OD828	1000	8.0	MgO	2 h	β
OS2036	1000	8.5	MgO	4 h	β
OS2039	1000	9.0	hBN	4 h	β and γ
OD817	1000	10	MgO	30 min	β and γ
OD876	1000	13	hBN	2 h	β and γ
OS2029	1300	8.5	MgO	2 h	β
OS2028	1300	9.0	MgO	2 h	β and γ
OS2025	1300	9.5	MgO	2 h	β and γ
OD831	1300	10	MgO	2 h	β and γ
OD874	1300	13	hBN	10 min	γ
OS2043	1500	9.0	MgO/BN	2 h	β and γ
OS2027	1600	9.0	MgO/BN	30 min	β
OD860	1600	9.5	MgO	2 h	β and γ
OS2016	1600	10	MgO	2 h	β and γ
OD812	1600	15	MgO	30 min	γ
OD871	1600	13	hBN	2 h	γ
OD872	1600	13	hBN	10 min	γ
OD935	1600	13	Pt	1 min	γ
OD918	1800	15	Pt	10 min	γ
OD895	2000	18	hBN	10 min	γ
OD920	900	9.0	Au/Pt	20 h	β
OD922	900	9.5	Au/Pt	20 h	β
OD928	850	13	Au	24 h	β and γ
OD930	500	13	Au	24 h	β
OD933	700	13	Au	24 h	β
OD976	1800	12	Al_2O_3	30 min	γ
OD975	2000	12	Al_2O_3	5 min	γ + T-B ₅₀
OD942	2100	15	Ta	5 min	γ + T-B ₅₀
OD891	2200	18	hBN	2 min	γ + T-B ₅₀
OD994	2000	7.0	Al_2O_3	5 min	β
OD999	2000	8.0	Al_2O_3	5 min	β
OD997	2000	9.5	Al_2O_3	5 min	β + T-B ₅₀
OD1001	2000	9.0	Al_2O_3	5 min	β + T-B ₅₀
OD1003	1700	9.5	Al_2O_3	15 min	β and γ
OD1008	1800	9.0	Al_2O_3	5 min	β
OD1009 (γ + T) ^a	1600	12.	Al_2O_3	50 min	γ
OD1011 (γ) ^b	1700	7.0	Al_2O_3	20 min	β
OD1013 (β + T) ^c	1700	7.0	Al_2O_3	20 min	β

^a γ + T-B₅₀ starting materials.

^b γ -boron starting material.

^c β + T-B₅₀ starting materials.

T-B₅₀ is also based on B₁₂ icosahedra, Kurakevych *et al.*²³ observed the crystallization of tetragonal boron T-B₅₀ phase as an intermediate one (from β -B₁₀₆ to γ -B₂₈) at HPHT. In our experiment, we studied β -B₁₀₆ at 2000 $^{\circ}\text{C}$ and high pressures of 9.5 and 12 GPa, and the quenched sample is pure boron using energy-dispersive x-ray spectroscopy analysis (see supplementary material, figure S1²⁸). Figure 2(a) shows the Raman spectra of the recovered products that were heated at 2000 $^{\circ}\text{C}$ for 5 min at 12 GPa and β -B₁₀₆. Because boron is a light element and poor x-ray scatterer, we did not obtain good-quality XRD patterns. However, the phase transition of boron is easy to clarify in Raman spectra, in which we can find color zones different from the optical image [Fig. 2(b)]. Raman spectra show that light gray and gray zones correspond

to γ -B₂₈, but Raman spectra of dark gray are different from the β -B₁₀₆, α -B₁₂,⁴ and γ -B₂₈. The same results were obtained at 15 GPa and 2100 $^{\circ}\text{C}$ and 18 GPa and 2200 $^{\circ}\text{C}$. Additionally, we conducted β -B₁₀₆ at 9.5 GPa and a similar temperature and quenched the sample to ambient conditions for Raman spectra. Some special grains appear in the sample from the microscopic image [Fig. 2(c)], and Raman spectra of these grains are the same as the dark gray of the quenched sample under higher pressure; the other area is β -B₁₀₆. As the XRD quality is very low, and it is difficult to identify phase. We prepared TEM foils [dark gray zone in Fig. 2(b)] using the FIB system for TEM observations. Figures 2(d) and 2(e) shows the TEM image and SAED patterns of TEM foils. The SAED patterns can be indexed as the diffraction patterns of the [1-10] zone axis of

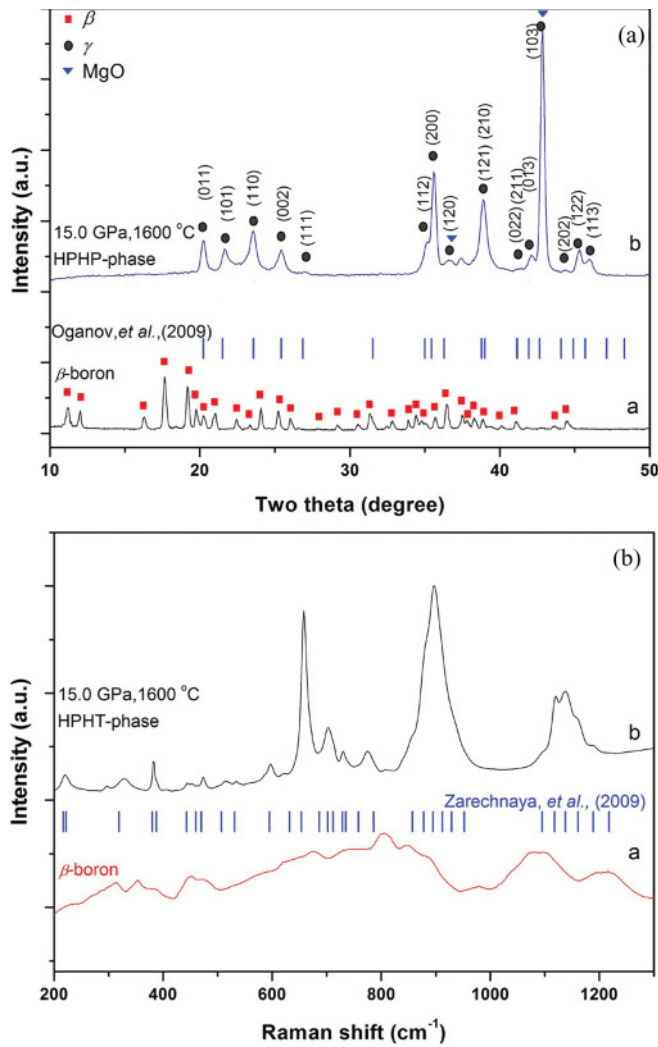


FIG. 1. (Color online) XRD patterns (a) and Raman spectra (b) of β -B₁₀₆ treated at 15 GPa and 1600 °C and β -B₁₀₆ and compared with previous experimental results from Oganov *et al.* (Ref. 1) and Zarechnaya *et al.* (Refs. 4 and 30).

T-B₅₀, and the lattice parameters are $a = 8.71 \text{ \AA}$ and $c = 5.00 \text{ \AA}$, which is in good agreement with the reference ($a = 8.73 \text{ \AA}$, $c = 5.03 \text{ \AA}$ ¹⁹ and $a = 8.75 \text{ \AA}$, $c = 5.06 \text{ \AA}$ ^{20,21}). Thus, we have observed the T-B₅₀ from β -B₁₀₆ at HPHT and presented the Raman spectra of T-B₅₀. Our results also suggest the T-B₅₀ is a pure boron phase and can be synthesized at HPHT.

To understand the relative phase stability of boron, we investigated the phase relations of γ -B₂₈, β -B₁₀₆, and T-B₅₀. Table I shows the experimental synthesis conditions and the characterization of the recovered samples, and Fig. 3 shows selected XRD patterns and Raman spectra of the quenched samples from HPHT conditions. Characteristic x-ray and Raman spectra of the starting material, β -B₁₀₆, are also presented in the bottom curves (a in Fig. 3). At high temperatures of 1300 °C, it has a similar XRD pattern [curve b, Fig. 3(a)] to that of β -B₁₀₆, and no phase transitions are detected at 8.5 GPa. At 9.0 GPa, we find that the peaks of γ -B₂₈ appear [curve c, Fig. 3(a)]. The peaks of β -B₁₀₆ decrease with increasing pressure. When pressure increases up to 10 GPa,

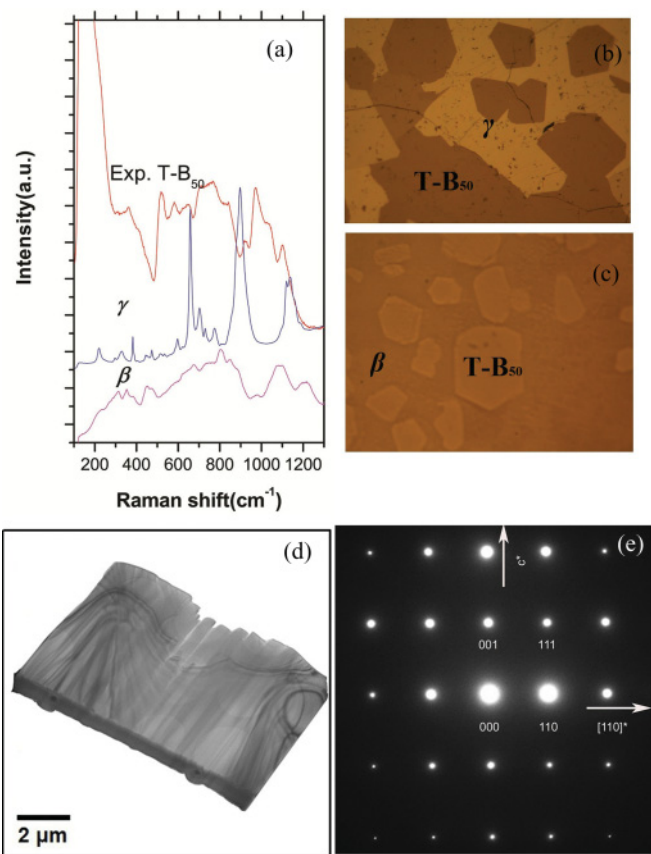


FIG. 2. (Color online) (a) Raman spectra of T-B₅₀ synthesized at 2000 °C and high pressures of 9.5 and 12 GPa compared with Raman spectra of β -B₁₀₆ and γ -B₂₈. (b) Optical photo of quenched sample at 12 GPa. (c) Optical photo of quenched sample at 9.5 GPa. (d) TEM image of the single-crystal foil. (e) SAED pattern shows the diffraction patterns of the [1-10] zone axis of T-B₅₀.

the diffraction pattern shows γ -boron and the peaks of β -B₁₀₆ almost disappear [curve d, Fig. 3(a)]. Raman spectra also demonstrate a drastic change. The Raman spectra of starting materials and quenched sample from 8.5 GPa and 1300 °C [curves a and b, Fig. 3(b)] are dominated by the β -B₁₀₆ phonon modes, whereas the spectra of 9.0 GPa or higher [curves c, d, and e; Fig. 3(b)] significantly differ from the previous two. Based on the XRD results and Raman spectra, we confirm the phase transition from β -B₁₀₆ to γ -B₂₈ between 8.5 GPa and 9.0 GPa below 1300 °C.

Samples treated to temperatures of 1000 °C and 1600 °C at different pressures were also investigated using XRD and Raman spectra. The samples usually underwent HPHT conditions for 2 h, although some samples were treated for 4 h or more than 20 h under P-T conditions near the phase boundary and at a relatively lower temperature. A combination of the XRD and Raman spectra results (Table I) [also see supplementary material, fig. S2(a)–(d)²⁸] reveals that the P-T conditions of the β -B₁₀₆ to γ -B₂₈ phase transition lie between 8.5 and 9.0 GPa and between 9.0 and 9.5 GPa under high temperatures of 1000 and 1600 °C, respectively.

To further understand the phase boundary of β -B₁₀₆ to T-B₅₀ and γ -B₂₈ to T-B₅₀, we conducted β -B₁₀₆ experiments at pressures between 7.0 and 18 GPa and temperatures of

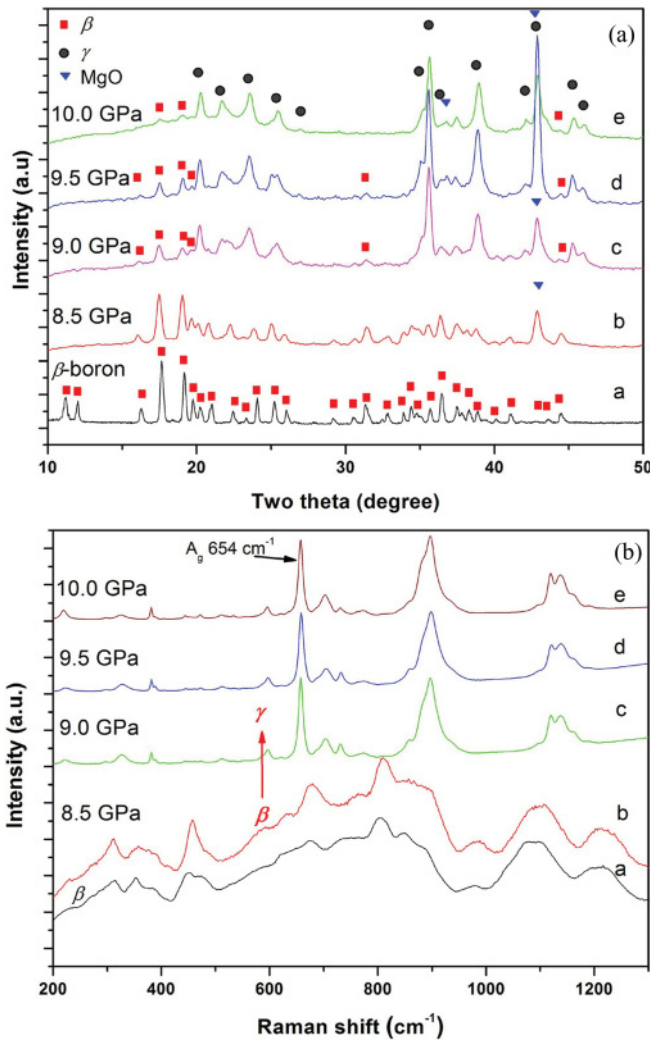


FIG. 3. (Color online) XRD patterns and Raman spectra of β -boron treated at HPHT and β -B₁₀₆. (a) XRD patterns, (b) Raman spectra.

1700–2200 °C, and we quenched the samples to ambient conditions for XRD and Raman spectra (Table I). Under high pressures of 12, 15, and 18 GPa, when β -B₁₀₆ is heated up to 1800, 1900, and 2000 °C, respectively, XRD and Raman spectra indicate that pure γ -B₂₈ is successfully synthesized. At similar pressures, the T-B₅₀ is produced at higher temperatures of 2000–2200 °C (Table I). However, it is difficult to synthesize pure T-B₅₀ according to our experimental results. Under lower pressures of 7.0 and 8.0 GPa and high temperature of 2000 °C, the quenched sample is pure β -B₁₀₆ from XRD and Raman spectra. When we increase the pressure to 9.0 GPa, β -B₁₀₆ and T-B₅₀ coexist in the quenched sample at the high temperature of 2000 °C, but it is pure β -B₁₀₆ at 1800 °C. Thus, we give a tentative phase boundary of γ -B₂₈ to T-B₅₀ and β -B₁₀₆ to T-B₅₀ according to our experimental results (Fig. 4).

Figure 4 shows the P-T region of the phase relations of β -B₁₀₆, γ -B₂₈, and T-B₅₀ compared with the results of Oganov *et al.*¹ and Zarechnaya *et al.*², and the inset shows the P-T conditions for synthesis of the T-192 phase from Oganov *et al.*¹ and Ma *et al.*⁵ In this P-T region, our β -B₁₀₆ to γ -B₂₈ phase boundary is in good agreement with Oganov’s theoretical

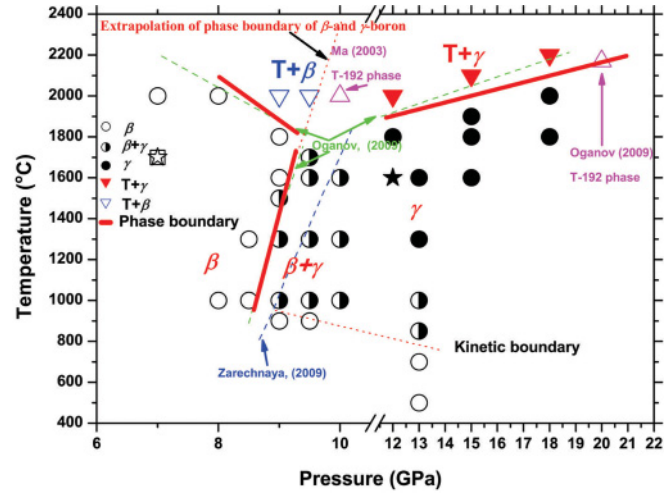


FIG. 4. (Color online) Phase relations of β -B₁₀₆ (open circles), γ -B₂₈ (solid circles), and T-B₅₀. The semisolid circles represent β -B₁₀₆ and γ -B₂₈ in coexistence, the open and solid inverse triangles are β -B₁₀₆ and T-B₅₀ mixtures, and the open and solid triangles are γ -B₂₈ and T-B₅₀ mixtures, respectively, and the triangles represent P-T conditions of the T-192 phase from Oganov *et al.* (Ref. 1) and Ma *et al.* (Ref. 5), respectively. The line is the phase boundary of β -B₁₀₆, γ -B₂₈, and T-192 boron, and the inset show the theoretical phase boundary from Oganov *et al.* (Ref. 1) and the tentative phase boundary from Zarechnaya *et al.* (Ref. 2). Reverse experiments are also shown in this figure; square is phase transition from γ -B₂₈ to β -B₁₀₆, open and solid stars present T-B₅₀ transformations back to β -B₁₀₆ and γ -B₂₈, respectively.

results and Zarechnaya’s DAC results. Our results indicate that the phase relations of β -B₁₀₆ and γ -B₂₈ have almost no pressure dependence. The other two phase boundaries (β -B₁₀₆/T-B₅₀ and γ -B₂₈/T-B₅₀) have not been reported so far on the basis of experimental data and prove that the T-B₅₀ phase is not only a pure boron phase but has a field of stability at high pressures and temperatures.

By extrapolation of the β -B₁₀₆ and γ -B₂₈ phase boundary, we find $\beta +$ T-B₅₀ is in the “phase stability” of β -B₁₀₆, and $\gamma +$ T-B₅₀ is in the phase stability of γ -B₂₈. This is why we synthesize a mixture of β -B₁₀₆ and T-B₅₀ at a lower pressure and a mixture of γ -B₂₈ and T-B₅₀ at a higher pressure. Additionally, we also examined γ -B₂₈, a mixture of γ -B₂₈ and T-B₅₀, and a mixture of β -B₁₀₆ and T-B₅₀ at 7.0 GPa and 1700 °C, 12 GPa and 1600 °C, and 7.0 GPa and 1700 °C, respectively. XRD and Raman spectra results show that γ -B₂₈ and T-B₅₀ transform back to β -B₁₀₆ and T-B₅₀ transforms back to γ -B₂₈ under the stability field of β -B₁₀₆ and γ -B₂₈, respectively. Combined with the previous results^{1,2,5} and our study, we find that β -B₁₀₆ transforms into γ -B₂₈ at high pressure and certain temperatures and then transforms back to β -B₁₀₆ at relatively low pressures (~9 GPa). With increasing temperature up to 2000 °C, β -B₁₀₆ will transform to T-B₅₀; however, β -B₁₀₆ transforms into γ -B₂₈ and then transforms into T-B₅₀ at relatively higher pressures (more than ~10 GPa). These results show that γ -B₂₈ is stable phase under a certain pressures (above ~9 GPa) in good agreement with previous theoretical results.¹ However, we did not observe the T-192 phase in our experiment. The phase

stability of T-B₅₀ is in the theoretical phase stability of the T-192 phase, and Kurakevych *et al.*²³ also found crystallization of the T-B₅₀ phase to be intermediate (between β -B₁₀₆ and γ -B₂₈), so we suggest T-B₅₀ could exist as an intermediate phase (along the phase boundary of the γ -B₂₈ to T-192 phase and the β -B₁₀₆ to T-192 phase from Oganov *et al.*¹ results). These results might indicate the reason behind the Ostwald rule of stages,^{34,35} which shows the possible phases, with intermediate values, of free Gibbs energy before the system has transformed into the thermodynamically stable phase with the most stable crystal structure. According to first principles calculations,¹ the T-192 phase should be stable in our experimental conditions. From the phase diagram, our experiments reveal that T-B₅₀ exists along the phase boundary of the γ -B₂₈ to T-192 phase and β -B₁₀₆ to T-192 phase.¹ The difference could be explained by the non-negligible 0 K configurational entropy of T-192 and T-B₅₀, which strongly decreases the free enthalpy at high temperatures. In our experimental conditions, the configurational entropy of T-192 should be greater than T-B₅₀, which is why we obtained just the T-B₅₀. If we continue heating to higher temperatures, the configurational entropy of T-192 will be less than T-B₅₀, and the system will transform into the thermodynamically stable phase with the most stable crystal structure (T-192). Thus, more experimental and theoretical studies on structural and phase stability of boron are strongly recommended, especially the thermodynamic phase relations between T-B₁₉₂ and T-B₅₀ at HPHT. Here, we also give the kinetic boundary of β -B₁₀₆ to γ -B₂₈. The results indicate that kinetic barriers decrease with increasing pressure, and no α -B₁₂ was found in our HPHT conditions.

IV. CONCLUSION

We synthesized γ -B₂₈ and T-B₅₀ from β -B₁₀₆ under HPHT using a multianvil press and investigated the phase relations of β -B₁₀₆, γ -B₂₈, and T-B₅₀. We demonstrate that γ -B₂₈ can be synthesized over a wide P-T range and that T-B₅₀ is obtained at higher temperatures and similar pressures, and we suggest that T-B₅₀ might be an intermediate phase formed for kinetic reasons (Ostwald rule) on the way from β -B₁₀₆ to T-192 and γ -B₂₈ to T-192.

On the basis of the XRD, Raman spectra, and TEM results, we present the experimental phase relations in boron at pressures up to 18 GPa and temperatures up to 2200 °C. We suggest that β -B₁₀₆ and γ -B₂₈ transform directly to T-B₅₀ at lower and higher pressure, respectively. Additionally, T-B₅₀ transforms back to β -B₁₀₆ and γ -B₂₈ during quenching under lower pressures and higher pressures, respectively. The results provide fundamental information for better understanding of the phase diagram of this interesting material. However, more experimental and theoretical studies on structural and mechanical properties are strongly recommended.

ACKNOWLEDGMENTS

This work is supported by JSPS Grants-in-Aid for Scientific Research under Grant No. 22 00029 and the G-COE Program. J.Q. thanks Leiming Fang, Fulong Wang, and Yongtao Zou for help with the experiment and A. R. Oganov and V. L. Solozhenko for valuable discussions.

*jiaqianqin@gmail.com

¹A. R. Oganov, J. Chen, C. Gatti, Y. Z. Ma, Y. M. Ma, C. W. Glass, Z. Liu, T. Yu, O. O. Kurakevych, and V. L. Solozhenko, *Nature* **457**, 863 (2009).

²E. Y. Zarechnaya, L. Dubrovinsky, N. Dubrovinskaia, Y. Filinchuk, D. Chernyshov, V. Dmitriev, N. Miyajima, A. El Goresy, H. F. Braun, S. Van Smaalen, I. Kantor, V. Prakapenka, M. Hanfland, A. S. Mikhaylushkin, I. A. Abrikosov, and S. I. Simak, *Phys. Rev. Lett.* **102**, 185501 (2009).

³G. Parakhonskiy, N. Dubrovinskaia, E. Bykova, R. Wirth, and L. Dubrovinsky, *Scientific Reports* **1**, 96 (2011).

⁴E. Y. Zarechnaya, L. Dubrovinsky, N. Dubrovinskaia, N. Miyajima, Y. Filinchuk, D. Chernyshov, and V. Dmitriev, *Sci. Technol. Adv. Mater.* **9**, 044209 (2008).

⁵Y. Z. Ma, C. T. Prewitt, G. T. Zou, H. K. Mao, and R. J. Hemley, *Phys. Rev. B* **67**, 174116 (2003).

⁶Y. M. Ma, J. S. Tse, D. D. Klug, and R. Ahuja, *Phys. Rev. B* **70**, 214107 (2004).

⁷K. Shirai, A. Masago, and H. Katayama-Yoshida, *Phys. Status Solidi B* **244**, 303 (2007).

⁸V. V. Brazhkin, T. Taniguchi, M. Akaishi, and S. V. Popova, *J. Mater. Res.* **19**, 1643 (2004).

⁹S. Shang, Y. Wang, R. Arroyave, and Z. Liu, *Phys. Rev. B* **75**, 092101 (2007).

¹⁰Y. L. Godec, O. O. Kurakevych, P. Munsch, G. Garbarino, and V. L. Solozhenko, *Solid State Commun.* **149**, 1356 (2009).

¹¹E. Amberger and W. Stumpf, *Boron, Gmelin Handbook of Inorganic Chemistry* (Springer-Verlag, Berlin, 1981), pp. 112.

¹²H. Bolmgren, T. Lundstrom, S. Okada, AIP Conference New York: American Institute of Physics **231**, 197 (1991).

¹³A. R. Oganov, V. L. Solozhenko, C. Gatti, O. O. Kurakevych, and Y. L. Godec, *J. Superhard Mater.* **33**, 363 (2011).

¹⁴B. E. Douglas and S. M. Ho, *Structure and Chemistry of Crystalline Solids* (Springer, New York, 2006).

¹⁵C. P. Talley, *Acta. Cryst.* **13**, 271 (1960).

¹⁶M. Vlasse, R. Naslain, J. S. Kasper, and K. Ploog, *J. Solid State Chem.* **28**, 289 (1979).

¹⁷E. Amberger and K. Ploog, *J. Less Common Met.* **23**, 21 (1971).

¹⁸J. L. Hoard and R. E. Hughes, in *The Chemistry of boron and Its Compounds*, edited by E. L. Muetterties (Wiley, New York, 1967), p. 25.

¹⁹A. W. Laubengayer, D. T. Hurd, A. E. Newkirk, and J. L. Hoard, *J. Am. Chem. Soc.* **65**, 1924 (1943).

²⁰J. L. Hoard, S. Geller, and R. E. Hughes, *J. Am. Chem. Soc.* **73**, 1892 (1951).

²¹J. L. Hoard, R. E. Hughes, and D. E. Sands, *J. Am. Chem. Soc.* **80**, 4507 (1958).

²²E. A. Ekimov and I. P. Zibrov, *Sci. Technol. Adv. Mater.* **12**, 055009 (2011).

²³O. O. Kurakevych, Y. L. Godec, T. Hammouda, and C. Goujon, e-print arXiv:1110.1731 (to be published).

- ²⁴V. L. Solozhenko, Y. L. Godec, and O. O. Kurakevych, *C. R. Chimie* **9**, 1472 (2006).
- ²⁵M. J. van Setten, M. A. Uijtewaal, G. A. de Wijs, and R. A. de Groot, *J. Am. Chem. Soc.* **129**, 2458 (2007).
- ²⁶K. Shirai, A. Masago, and H. Katayama-Yoshida, *Phys. Status Solidi B* **241**, 3161 (2004).
- ²⁷A. Masago, K. Shirai, and H. Katayama-Yoshida, *Phys. Rev. B* **73**, 104102 (2006).
- ²⁸See Supplemental Material at <http://link.aps.org/supplemental/10.1103/PhysRevB.85.014107> for additional information on experimental and theoretical methods and results.
- ²⁹T. Irifune, M. Isshiki, and S. Sakamoto, *Earth Planet. Sci. Lett.* **239**, 98 (2005).
- ³⁰E. Y. Zarechnaya, N. Dubrovinskaia, and L. Dubrovinsky, *High Press. Res.* **29**, 530 (2009).
- ³¹C. Dong, *J. Appl. Cryst.* **32**, 838 (1999).
- ³²C. Jiang, Z. J. Lin, J. Z. Zhang, and Y. S. Zhao, *Appl. Phys. Lett.* **94**, 191906 (2009).
- ³³Q. Xia, J. Yi, Y. Li, Y. Peng, H. Wang, and C. Zhou, *Solid State Commun.* **150**, 605 (2010).
- ³⁴W. Ostwald, *Z. Phys. Chem.* **22**, 289 (1897).
- ³⁵T. Threlfall, *Org. Proc. Res. Dev.* **7**, 1017 (2003).